

# Reflective UV Sensor

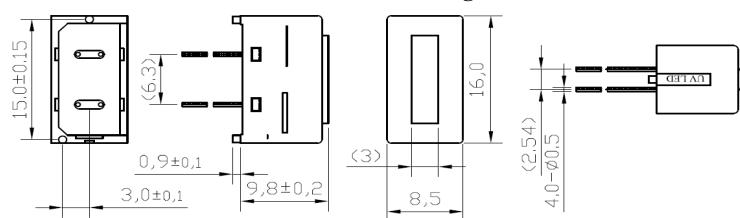
## GUVF-P12MD



<b>Features</b>	Light Emission Wavelength - 365nm Emitting part- Visible range absorbing filter Receiving part - UV absorbing filter Responding to fluorescence ink
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<b>Applications</b>	Money detecting Counterfeits bill detecting
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### 1. Emitting Part

#### Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Remark
Forward Current	I <sub>F</sub>		25	mA	
Pulse Forward Current	I <sub>FP</sub>		80	mA	
Allowed Reverse Voltage	I <sub>R</sub>		85	mA	
Power Dissipation	P <sub>D</sub>		100	mW	
Operation Temperature	T <sub>opr</sub>	-30	85	°C	
Storage Temperature	T <sub>stg</sub>	-40	100	°C	
Soldering Temperature *	T <sub>sol</sub>		330	°C	within 2 sec.

\* For Max.2 seconds at the position of 3mm from the package.

\* At PWB Flow Soldering unsupported.

#### Characteristics (at 25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Forward Voltage	V <sub>F</sub>	-	(3.4)	4.0	V	I <sub>F</sub> =10[mA]
Peak Wavelength * *	λ <sub>P</sub>	360	365	370	nm	I <sub>F</sub> =10[mA]

\* \* Peak Wavelength Measurement allowance is ±3nm

### 2. Receiving Part

#### Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Remark
Reverse Voltage	I <sub>R</sub>		30	V	
Operation Temperature	T <sub>opr</sub>	-25	90	°C	
Storage Temperature	T <sub>stg</sub>	-30	100	°C	
Soldering Temperature *	T <sub>sol</sub>		330	°C	within 2 sec.

\* For Max. 2 seconds at the position of 3mm from the package.

\* At PWB Flow Soldering unsupported.

### Characteristics (at 25 °C)

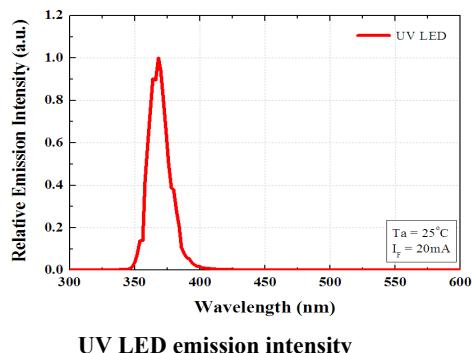
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Short circuit current * *	I <sub>SC</sub>	40	160	180	nA	I <sub>F</sub> =10mA
Current leak current * * *	I <sub>LEAK</sub>			20	nA	I <sub>F</sub> =10mA
Dark current	I <sub>D</sub>			10.0	nA	V <sub>R</sub> =10V
Capacitance	C <sub>T</sub>		50		pF	V <sub>R</sub> =0V, f=1MHz
Temperature coefficient of V <sub>O</sub> C	αt		-2.2		mV/°C	
Temperature coefficient of I <sub>SC</sub>	βt		0.18		%/°C	
Spectral sensitivity	λ	450		1,050	nm	
Peak wavelength	λ <sub>P</sub>		880		nm	
Half angle	Δθ		±60		deg.	

\* \* d=2.0mm, 90% Reflective paper

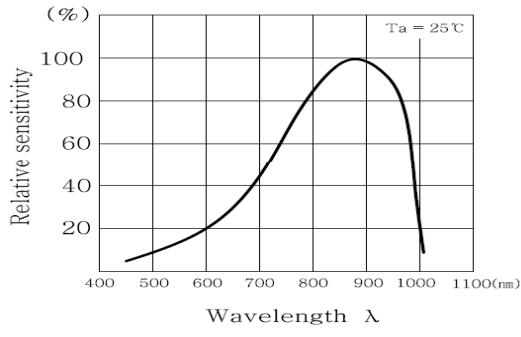
\* \* \* I<sub>LEAK</sub> @ No object, in dark

※ Anode is connected to case.

### 3. Characteristic spectrums



UV LED emission intensity



Responsivity of receiving sensor

### 4. Measurement conditions

- 1 cycle of test should be completed within 5 minutes.
- Left machine power-off at least 30 minute then for testing.
- To use the wordings side of Dummy.

\* This spec. sheet applied to GUVF-P12MD since August 20, 2012